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- *EPIC*TM (Enhanced-Performance Implanted CMOS) Submicron Process
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Typical V_{OLP} (Output Ground Bounce)
 < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 > 2 V at V_{CC} = 3.3 V, T_A = 25°C
- Inputs Accept Voltages to 5.5 V
- Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), and Thin Shrink Small-Outline (PW) Packages, Ceramic Flat (W) Package, Ceramic Chip Carriers (FK), and DIPs (J)

description

The SN54LVC86A quadruple 2-input exclusive-OR gate is designed for 2.7-V to 3.6-V V_{CC} operation and the SN74LVC86A quadruple 2-input exclusive-OR gate is designed for 1.65-V to 3.6-V V_{CC} operation.

The 'LVC86A devices perform the Boolean function $Y = A \oplus B$ or $Y = \overline{AB} + A\overline{B}$ in positive logic.

A common application is as a true/complement element. If one of the inputs is low, the other input is reproduced in true form at the output. If one of the inputs is high, the signal on the other input is reproduced inverted at the output.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

The SN54LVC86A is characterized for operation over the full military temperature range of -55° C to 125° C. The SN74LVC86A is characterized for operation from -40° C to 85° C.

	(each gate)										
	INP	UTS	OUTPUT								
	Α	В	Y								
Г	L	L	L								
	L	Н	Н								
	Н	L	Н								
	Н	Н	L								

FUNCTION TABLE



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

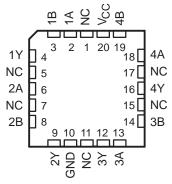


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SN54LVC86A J OR W PACKAGE
SN74LVC86A D, DB, DGV, OR PW PACKAGE

1A 1 14 V _{CC} 1B 2 13 4B 1Y 3 12 4A 2A 4 11 4Y 2B 5 10 3B 2Y 6 9 3A GND 7 8 3Y										
	1B [1Y [2A [2B [2 3 4 5 6	υ	13 12 11 10 9	þ	4A 4Y 3B 3A				

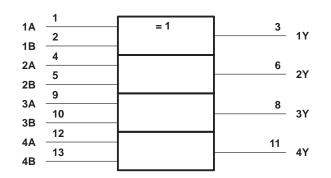
SN54LVC86A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

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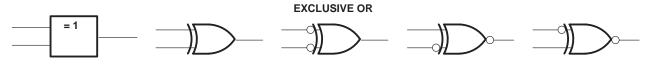
logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, DB, DGV, J, PW, and W packages.

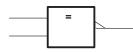
exclusive-OR logic

An exclusive-OR gate has many applications, some of which can be represented better by alternative logic symbols.

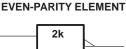


These five equivalent exclusive-OR symbols are valid for an SN74LVC86A gate in positive logic; negation may be shown at any two ports.

LOGIC-IDENTITY ELEMENT



The output is active (low) if all inputs stand at the same logic level (i.e., A = B).



The output is active (low) if an even number of inputs (i.e., 0 or 2) are active.

ODD-PARITY ELEMENT



The output is active (high) if an odd number of inputs (i.e., only 1 of the 2) are active.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage range, V_{CC} Input voltage range, V_I (see Note 1) Output voltage range, V_O (see Notes 1 and 2) Input clamp current, I_{IK} ($V_I < 0$) Output clamp current, I_{OK} ($V_O < 0$)		
Continuous output current, I_O Continuous current through V _{CC} or GND Package thermal impedance, θ_{JA} (see Note 3)		±50 mA ±100 mA
	DB package DGV package PW package	
Storage temperature range, T _{stg}		

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. The value of V_{CC} is provided in the recommended operating conditions table.
- 3. The package thermal impedance is calculated in accordance with JESD 51.



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recommended operating conditions (see Note 4)

			SN54LVC86A		SN74L	VC86A		
			MIN	MAX	MIN	MAX	UNIT	
Vee	Supply voltage	Operating	2	3.6	1.65	3.6	V	
VCC	Supply voltage	Data retention only	1.5		1.5		V	
		V _{CC} = 1.65 V to 1.95 V			$0.65 \times V_{CC}$			
VIH	High-level input voltage	V_{CC} = 2.3 V to 2.7 V			1.7		V	
VIL		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		2			
VIL		V _{CC} = 1.65 V to 1.95 V				$0.35 \times V_{CC}$		
	Low-level input voltage	V_{CC} = 2.3 V to 2.7 V				0.7	V	
		$V_{CC} = 2.7 V \text{ to } 3.6 V$		0.8		0.8		
VI	Input voltage		0	5.5	0	5.5	V	
VO	Output voltage		0	VCC	0	VCC	V	
		V _{CC} = 1.65 V				-4		
lou	High-level output current	$V_{CC} = 2.3 V$				-8	mA	
ЮН		$V_{CC} = 2.7 V$		-12		-12	IIIA	
		$V_{CC} = 3 V$		-24		-24		
		V _{CC} = 1.65 V				4		
la:	Low-level output current	$V_{CC} = 2.3 V$				8	mA	
IOL		$V_{CC} = 2.7 V$		12		12	IIIA	
		$V_{CC} = 3 V$		24		24		
$\Delta t / \Delta v$	Input transition rise or fall rate		0	9	0	9	ns/V	
TA	Operating free-air temperature		-55	125	-40	85	°C	

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	TEST CONDITIONS		SN54LVC86A			SN74LVC86A			UNIT	
PARAMETER	TEST CONDITIONS	Vcc	MIN	TYP†	MAX	MIN	TYP [†]	MAX	UNIT	
	100	1.65 V to 3.6 V				V _{CC} -0	.2			
	I _{OH} = -100 μA	2.7 V to 3.6 V	V _{CC} -0	.2						
	$I_{OH} = -4 \text{ mA}$	1.65 V				1.2				
VOH	I _{OH} = -8 mA	2.3 V				1.7			V	
	12	2.7 V	2.2			2.2				
	$I_{OH} = -12 \text{ mA}$	3 V	2.4			2.4				
	I _{OH} = -24 mA	3 V	2.2			2.2				
	100	1.65 V to 3.6 V				0.2		0.2		
	I _{OL} = 100 μA	2.7 V to 3.6 V 0		0.2						
Mar	I _{OL} = 4 mA	1.65 V						0.45	V	
VOL	I _{OL} = 8 mA	2.3 V						0.7	V V	
	I _{OL} = 12 mA	2.7 V			0.4			0.4		
	I _{OL} = 24 mA	3 V			0.55			0.55		
Ц	$V_I = 5.5 V \text{ or GND}$	3.6 V			±5			±5	μA	
ICC	$V_{I} = V_{CC} \text{ or GND}, \qquad I_{O} = 0$	3.6 V			10			10	μA	
ΔICC	One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND	2.7 V to 3.6 V			500			500	μΑ	
Ci	$V_{I} = V_{CC}$ or GND	3.3 V		5			5		pF	

[†] All typical values are at V_{CC} = 3.3 V, T_A = 25° C.

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
			MIN	MAX	MIN	MAX	
^t pd	A	Y		5.6	1	4.6	ns

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

					SN74L	VC86A		-		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V	V _{CC} = ± 0.2	2.5 V 2 V	V _{CC} =	2.7 V	V _{CC} = ± 0.3	3.3 V 3 V	UNIT
			TYP	MIN	MAX	MIN	MAX	MIN	MAX	
^t pd	A	Y	13.6	1	7.6		5.6	1	4.6	ns
^t sk(o) [‡]									1	ns

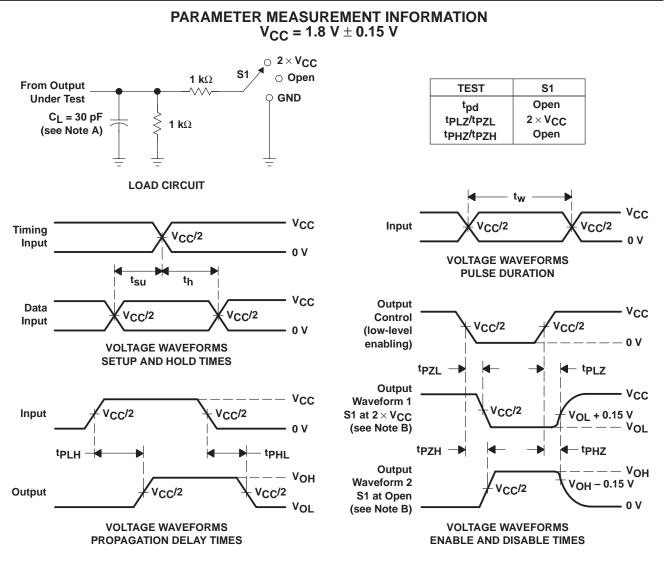
[‡]Skew between any two outputs of the same package switching in the same direction

operating characteristics, $T_A = 25^{\circ}C$

PARAMETER		TEST	V _{CC} = 1.8 V	V _{CC} = 2.5 V	V _{CC} = 3.3 V	UNIT	
	FARAIVIETER	CONDITIONS	TYP	TYP	TYP	UNIT	
Cpd	Power dissipation capacitance per gate	f = 10 MHz	6.5	7.5	8.5	pF	



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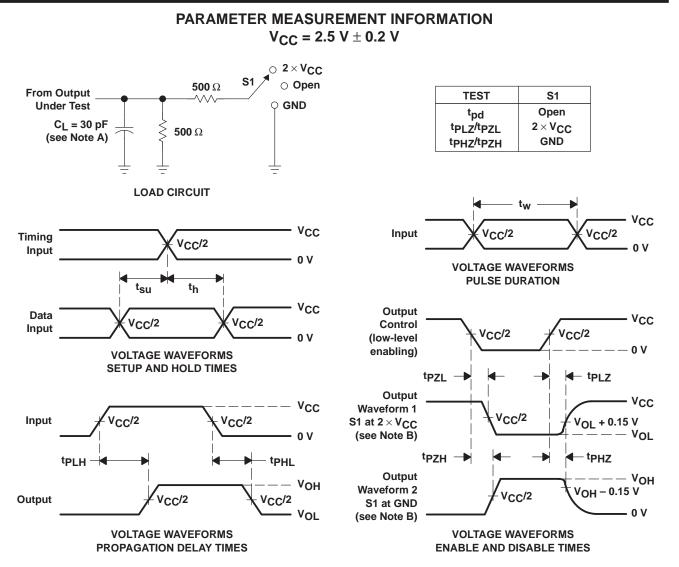


- NOTES: A. CL includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f \leq 2 ns, t_f \leq 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms



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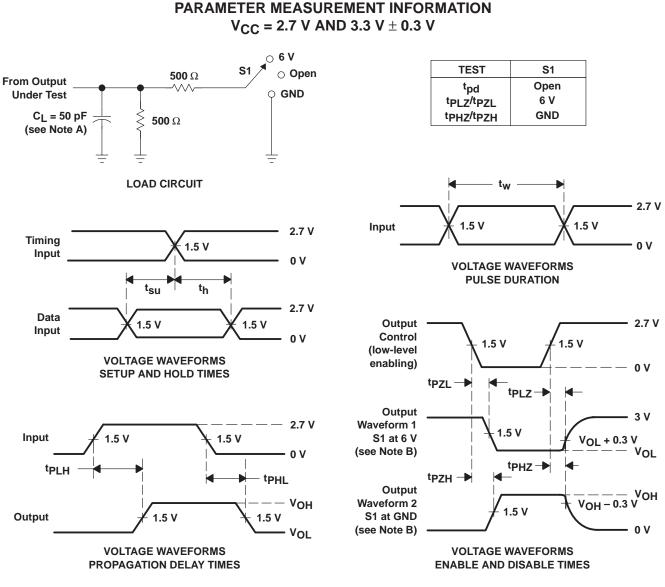
- NOTES: A. CL includes probe and jig capacitance.
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 - D. The outputs are measured one at a time with one transition per measurement.

 - E. tPLZ and tPHZ are the same as tdis.
 - F. tp7I and tp7H are the same as ten.
 - G. tPLH and tPHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms



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- NOTES: A. CL includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_r \leq 2.5 ns, t_f \leq 2.5 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpl 7 and tpH7 are the same as tdis.
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 3. Load Circuit and Voltage Waveforms



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